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### ARTICLE

# Anomalous Second Harmonic Generation (SHG) Response in MBPO<sub>5</sub> (M=Sr, Ba)

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Large sized ultraviolet (UV) nonlinear optical (NLO) crystals  $SrBPO_5$  and  $BaBPO_5$  have been obtained successfully by top-seeded solution growth method in order to study the mechanism of second harmonic generation (SHG) effect in borophosphates. Optical and thermal properties have been measured.  $SrBPO_5$  and  $BaBPO_5$  display large experimental gaps (6.44 and 6.14 eV) and moderate SHG coefficients (0.57 and 0.43 times of KH<sub>2</sub>PO<sub>4</sub> (KDP)). More importantly, based on the further insight into the relationship between nonlinear optical properties and crystal structure within density functional theory (DFT), we discover that  $BO_4$  groups and metal cations take essential roles in SHG effect of  $MBPO_5$  (M=Sr, Ba) but not PO<sub>4</sub> groups as expected. Moreover,  $PO_4$  groups play a counteractive role in  $BaBPO_5$  because of indirect influence from metal cations.

#### Introduction

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The solid state laser has many significant applications in a broad area, such as laser micromaching, semiconductor photolithography, photochemical synthesis, laser communication and so on. Owing to the ability to shorten the wavelength of light based on the process of second-harmonic generation (SHG), the nonlinear optical (NLO) crystals become the key material used in the frequency conversion device. After continuous efforts over several decades, many excellent NLO crystals were obtained. The most advanced, commercially available benchmark NLO materials for ultraviolet-visible (UV-vis) region are borates or phosphates, such as KH<sub>2</sub>PO<sub>4</sub>  $(\text{KDP})^1$ ,  $\text{KTiOPO}_4$   $(\text{KTP})^2$ , <sup>3</sup>,  $\beta$ -BaB<sub>2</sub>O<sub>4</sub>  $(\text{BBO})^4$ , LiB<sub>3</sub>O<sub>5</sub>(LBO)<sup>5</sup>, etc. In the last few years, many novel borate crystals and potential applications have been reported in the UV/Deep-UV region, such as NaBeB<sub>3</sub>O<sub>6</sub><sup>6</sup> K<sub>3</sub>B<sub>6</sub>O<sub>10</sub>Cl<sup>7</sup>, Cs<sub>2</sub>B<sub>4</sub>SiO<sub>9</sub><sup>8</sup>, Ba<sub>4</sub>B<sub>11</sub>O<sub>20</sub>F<sup>9</sup> with large powder SHG responses about 1.6, 4, 4.6, 10 times of KH<sub>2</sub>PO<sub>4</sub> (KDP) and short UV cutoff edges of 200, 180, 190, 175 nm, respectively. Recently,  $Li_4Sr(BO_3)_2^{10}$  which is expected as a rival of  $KBe_2BO_3F_2$  (KBBF)<sup>11, 12</sup>, was obtained. And some phosphates such as  $Ba_3P_3O_{10}Cl^{13}$ ,  $Rb_2Ba_3(PO_3)_3^{14}$  have also drawn much attention ascribed to their short UV cutoff edges (180, 163 nm) but with weak SHG effect. Therefore, it is in urgent need of crystals with good deep UV NLO characteristics.

It is interesting to note that thanks to their complex anionic groups built of  $BO_4$ ,  $BO_3$ , and  $PO_4$  tetrahedra, borophosphates

exhibit rich chemistry structure and many potential applications<sup>15-18</sup>. The crystal chemistry of borophosphates with anionic partial structures mainly built from tetrahedral building units reveals a large structural variety, similar to that of silicates and alum silicates. The primary BO4, BO3 and PO4 building units can interconnect to form complex anionic structures from isolated species, oligomers, rings, chains, layers to framework<sup>19</sup>. Therefore, there is lots of room to explore novel compounds for the considerable variety in the chemical structure. For example, the MBPO<sub>5</sub> (M=Sr, Ba, Ca) compounds belong to the stillwellite structural type, and contain single chains of the BO<sub>4</sub> tetrahedra running parallel to [001] which are linked to terminal PO<sub>4</sub> tetrahedra to form spiral chains<sup>20, 21</sup>. BPO<sub>4</sub> whose structure is similar to that of silica<sup>22</sup> also contains  $BO_4$  and  $PO_4$  groups. Except for tetrahedrally coordinated  $B^{3+}$ and P<sup>5+</sup>, Co<sub>5</sub>BP<sub>3</sub>O<sub>14</sub> is the first borophosphate with planar BO<sub>3</sub> groups connected to PO<sub>4</sub> tetrahedra<sup>23</sup>. In the respect of crystal structure, Kniep and co-workers have systematically studied borophosphate compounds in their review articles<sup>24, 25</sup>. Among various structures, B-O-B or B-O-P connections are observed commonly and made up of BO<sub>3</sub>, BO<sub>4</sub> and PO<sub>4</sub> tetrahedra sharing common corners. The P-O-P connections have also been found in the borophosphates anions, such as,  $Cs_2Cr_3(BP_4O_{14})(P_4O_{13})$ ,  $CsFe(BP_3O_{11})$ ,  $Li_2Cs_2B_2P_4O_{15}$  and Li<sub>3</sub>M<sub>2</sub>BP<sub>4</sub>O<sub>14</sub> (M=K, Rb)<sup>26</sup>.

Owing to the various structures of borophosphates, they exhibit different properties. Because of the absence of dangling

bonds of oxygen in BO<sub>4</sub> groups, several borophosphates with short UV cutoff edge have been found. There are SrBPO<sub>5</sub><sup>20</sup>, BaBPO<sub>5</sub><sup>21</sup>, BPO<sub>4</sub><sup>27</sup>, Sr<sub>6</sub>BP<sub>5</sub>O<sub>20</sub><sup>28</sup>, and their cutoff edges are below 185, 180, 134 and 200 nm, respectively. Unfortunately, the SHG intensities are very weak except BPO<sub>4</sub>. It is also a common character in borophosphates or phosphates. Luckily, there are several materials with relatively large SHG responses, such as BPO<sub>4</sub> and NH<sub>4</sub>H<sub>2</sub>PO<sub>4</sub> (ADP) with the magnitude of almost double as that of KDP. In fact, for the SHG effect, the magnitude as large as that of KDP is enough for applications in UV or deep-UV wavelength<sup>29</sup>. Therefore, a fully understanding of the mechanism of NLO effects in borophosphate crystals can help us to design and search new excellent NLO crystals more efficiently. Generally, compared with the BO3 group, the BO4 group in borates is considered to have a neglectable contribution to SHG effect. While one question remains open that what the role of BO4 is, especially in a series of borophosphates which only contain BO<sub>4</sub> and PO<sub>4</sub> anionic groups. To deeply understand their inner mechanism of NLO effects of borophosphates and then guide the design of new NLO borophosphate materials, four aspects need to be clarified: i) what the NLO-active units are, ii) how the arrangements of the NLO-active units affect macroscopic NLO effects, iii) what the relationship between NLO properties and crystal structures is, iv) how to enhance the SHG effect.

Until now, several theories have been proposed to help chemists and material scientists to design and search new NLO materials with large SHG effect. The "anionic group theory"<sup>30</sup>. proposed by Chen et al., has proven to be successful in searching new NLO borate crystals with large SHG effects, such as BBO (5.8×KDP), LBO (about 3×KDP), etc. Besides, some materials with large SHG effect which owes to the combination of second-order Jahn-Teller units with diverse boron-oxygen functional units have emerged, typical examples are Cd<sub>4</sub>BiO(BO<sub>3</sub>)<sub>3</sub> (6×KDP)<sup>31</sup>, Pb<sub>2</sub>B<sub>5</sub>O<sub>9</sub>I (13.5×KDP)<sup>32</sup>. In order to get Deep-UV NLO crystals, another rigorous prerequisite for UV/Deep-UV region is the wide transparence, which is expected to unhinder the role of NLO-active structural units. Consequently, the introduction of SOJT units usually conflicts with the short UV cutoff edge. Then, a modified bond valence sum method<sup>33-35</sup> has been put forward to shorten the cutoff edge. Via controlling ambient coordination environment surrounding the oxygen atoms, the band gap can be increased due to the amplitude of eliminating the nonbonding orbitals. Notable compounds are Al-containing borates: K<sub>2</sub>Al<sub>2</sub>B<sub>2</sub>O<sub>7</sub> (KAB)<sup>36</sup>, Na<sub>2</sub>Al<sub>2</sub>B<sub>2</sub>O<sub>7</sub> (NABO)<sup>37</sup> and Cs<sub>2</sub>Al<sub>2</sub>B<sub>2</sub>O<sub>7</sub> (CABO), or Be-containing borates:  $Sr_2Be_2B_2O_7$  (SBBO)<sup>38</sup>, KBBF, MM'Be<sub>2</sub>B<sub>2</sub>O<sub>6</sub>F  $(M=Na, M'=Ca; M=K, M'=Ca, Sr)^{39}$ . Therefore, it is necessary to investigate the insight of relationship between crystal structures and NLO properties. Especially, to our best knowledge, the contribution of anionic tetrahedral groups in borophosphates for SHG still lacks investigation. Accordingly, it will be beneficial to design and search new excellent borophosphate crystals.

Herein, the isostructural compounds SrBPO<sub>5</sub> and BaBPO<sub>5</sub>, which have short UV cutoff edges of 180 and 185 nm and relatively small SHG intensities of 0.439 and 0.570 KDP, were studied as a demonstration. In order to characterize their properties accurately, the SrBPO<sub>5</sub> and BaBPO<sub>5</sub> crystals were grown by the top-seeded solution method. And the additional measurements such as DTA, optical uniformity measurement, were made. Detailed investigations on the crystal structure, electronic structure and optical properties of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> have been performed based on DFT calculation. To insight into the relationship between electronic structure and properties, SHG-density, band-resolved method, real-space atom-cutting method are adopted. The results of calculation agree well with those obtained from the experiments but the NLO-active units are not what we expected. Previously, if there are BO4 and PO4 groups in a compound, the PO4 groups are considered to be the main contributor of SHG because borates containing BO4 groups could possess a SHG effect smaller than that containing BO<sub>3</sub> groups<sup>20, 30</sup>. Anomalously, through precise analysis based on SHG-density and bandresolved methods, we found that the BO4 groups and metal cations give the main contribution to SHG effect of MBPO<sub>5</sub> but not the PO<sub>4</sub> groups as expected. What is more, the PO<sub>4</sub> groups even show the counteractive contribution in BaBPO<sub>5</sub> because of indirect influence from the cations.

#### Experimental

#### Synthesis and Crystal Growth

Polycrystalline samples of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> were synthesized by traditional solid-state reaction techniques. Analytically pure SrCO<sub>3</sub> (for SrBPO<sub>5</sub>) or BaCO<sub>3</sub> (for BaBPO<sub>5</sub>), H<sub>3</sub>BO<sub>3</sub> and NH<sub>4</sub>H<sub>2</sub>PO<sub>4</sub> were weighted as stoichiometric ratio and mixed in an agate mortar, and then packed into a platinum crucible. After preheating at 500 °C for 20 h in muffle furnace, the mixture was cooled to ambient temperature and grinded, pressed. Then, the products were heat up to 900 °C for 72 h (for SrBPO<sub>5</sub>) and 48 h (for BaBPO<sub>5</sub>), and cooled to room temperature again. The results were checked by powder X-ray diffraction, and single-phase powders of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> were obtained when repeated heat treatment caused no further changes in the powder X-ray diffraction pattern.

The flux method is necessary for the crystal growth of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> because they are incongruently melting compounds. As they were described in previous paper<sup>20, 21</sup>, the top-seeded solution growth method was used to grow the single crystals, BPO<sub>4</sub> (for SrBPO<sub>5</sub>) and Li<sub>4</sub>P<sub>2</sub>O<sub>7</sub> (BaBPO<sub>5</sub>) was used as the fluxes. The crystals were then obtained after drawn out of the solution surface, cooled to room temperature at a gradient of 20 °C/h, then slowly taken out from the furnace.

#### **Powder X-ray Diffraction**

A Bruker D2 ADVANCE X-ray diffract meter equipped with a monochromatic Cu K $\alpha$  radiation ( $\lambda = 1.5418$  Å) was used to measure the powder X-Ray Diffraction. The angular range from 10° to 70° (2 $\theta$ ) was recorded, with a scan step width of 0.02°

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and a rate of 10 s step<sup>-1</sup>. Theoretical simulation was conducted on the basis of the single crystal crystallographic data. The powder X-ray diffraction patterns of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> are shown in Figure S1.

#### Numerical Calculation Details and Methods

#### **Electronic Structure and Linear Optical Properties**

The first-principles calculations were performed by the CASTEP<sup>40</sup>, a plane-wave pseudopotential package based on the DFT. During the calculation, geometry optimization was performed using the BFGS minimization technique. The geometry optimization was converged criterion that the residual forces on the atoms were less than 0.01 eV/Å, the displacements of atoms were less than  $5 \times 10^{-4}$  Å, and the energy change was less than  $5.0 \times 10^{-6}$  eV/atom. After a series of successful tests, the exchange-correlation functional we chose was the generalized gradient approximation (GGA) with Perdew-Burke-Ernzerhof (PBE) functional. The normconserving pseudopotential (NCP) was used, the valence electrons were Sr-4s<sup>2</sup>4p<sup>6</sup>5s<sup>2</sup>, B-2s<sup>2</sup>2p<sup>1</sup>, O-2s<sup>2</sup>2p<sup>4</sup>, and P-2s<sup>2</sup>2p<sup>3</sup> respectively. The energy cutoff of plane wave's basis set was 830 eV, and the Brillouin zone was composed of  $4 \times 4 \times 4$ Monkhorst-Pack k-point sampling with a separation of 0.04 Å<sup>-1</sup>. We kept the default values of the CASTEP code on the aspect of the other calculation parameters and convergent criteria. The properties of BaBPO<sub>5</sub> were calculated in the same condition except for the valence electrons of  $Ba-5s^25p^66s^2$ .

"Scissors" correction approximation was implemented by moving all of the conduction bands off valence band with the gap correction  $\Delta$  (the difference between calculated bang gap and experimental one). In the scissors operator<sup>41-43</sup>, the momentum matrix elements should be modified. The correlative renormalization of the moment matrix elements under the gap correction is satisfied:<sup>44</sup>

$$P_{nm} \rightarrow P_{nm} (\omega_{nm} + \Delta/\hbar (\delta_{nc} - \delta_{mc}))/\omega_{nm}$$

Here,  $(\delta_{nc}-\delta_{mc})$  is the gap correction of the couples of bands between one valence and one conduction band state. In this process, as the GGA wave functions approach the true quasiparticle wave function<sup>45, 46</sup>, there is a hypothesis that the **r**<sub>mn</sub> mnmatrix elements is invariant.

# Methology for Probing SHG Contribution from Electronic States

The so-called length-gauge formalism derived by Aversa and Sipe<sup>47</sup> was adopted. At a zero frequency, the static second-order nonlinear susceptibilities can be ascribed to Virtual-Hole (VH), Virtual-Electron (VE) and Two-Band (TB) processe<sup>48</sup>.

$$\chi_{\alpha\beta\gamma}^{(2)} = \chi_{\alpha\beta\gamma}^{(2)} (\text{VE}) + \chi_{\alpha\beta\gamma}^{(2)} (\text{VH}) + \chi_{\alpha\beta\gamma}^{(2)} (\text{two-bands}) \cdot (1)$$

Where  $\chi_{\alpha\beta\gamma}^{(2)}(VE)$ ,  $\chi_{\alpha\beta\gamma}^{(2)}(VH)$ , and  $\chi_{\alpha\beta\gamma}^{(2)}(two bands)$  are computed with the formulas as follows:

$$\chi_{\alpha\beta\gamma}^{(2)}(VE) = \frac{e^3}{2\hbar m^3} \sum_{vcc'} \int \frac{d^3k}{4\pi^3} P(\alpha\beta\gamma) \operatorname{Im}\left[P_{cv}^{\alpha} P_{cc'}^{\beta} P_{c'v}^{\gamma}\right] \frac{1}{\omega_{cv}^3 \omega_{vc'}^2} + \frac{2}{\omega_{vc}^4 \omega_{c'v}}\right]$$
(2)

$$\chi_{\alpha\beta\gamma}^{(2)}(VH) = \frac{e^3}{2\hbar m^3} \sum_{vv'c} \int \frac{d^3k}{4\pi^3} P(\alpha\beta\gamma) \operatorname{Im} \left[ P^{\alpha}_{vv'} P^{\beta}_{cv'} P^{\gamma}_{cv} \right] \frac{1}{\omega^3_{cv} \omega^2_{vc}} + \frac{2}{\omega^4_{vc} \omega_{cv'}}$$
(3)

$$\chi_{\alpha\beta\gamma}^{(2)}(two-bands) = \frac{e^3}{2\hbar m^3} \sum_{vc} \int \frac{d^3k}{4\pi^3} P(\alpha\beta\gamma) \frac{\mathrm{Im} \left[ P_{vc}^{\alpha} P_{cv}^{\beta} (P_{vv}^{\gamma} - P_{cc}^{\gamma}) \right]}{\omega_{vc}^5}$$
(4)

Here,  $\alpha$ ,  $\beta$ ,  $\gamma$  are Cartesian components, and v/v', c/c' denote valence bands (VBs) and conduction bands (CBs). And P( $\alpha\beta\gamma$ ),  $\hbar\omega_{ij}$  and  $P^{\alpha}_{\ ij}$  refer to full permutation, the band energy difference and momentum matrix elements, respectively.

The band-resolved method, revealing the effective values of individual electronic states in SHG coefficients, comes forward to emphasize the two out of three band indices for  $\chi_{\alpha\beta\gamma}^{(2)}(VE)$  or  $\chi_{\alpha\beta\gamma}^{(2)}(VH)$  in equations (2) and (3). As a result, the SHG effect of orbital contribution is divided into occupied and unoccupied bands. Therefore, the analysis scheme exhibits the orbital contributions of total  $\chi^{(2)}$  with level by level vividly. In this work, the integral contribution of the band-resolved  $\chi^{(2)}$  in VE and VH processes was calculated further, which can show the integral SHG contribution of the corresponding energy region and the contribution of valence bands and conduction bands<sup>49</sup>. So we can use it to identify and further research the main states having contribution in a SHG process.

There is another more vivid method called SHG-density<sup>50</sup> which can illuminate the SHG response further in complex electronic structure we researched. The SHG-density method was performed by using the effective SHG of each occupied or unoccupied band as weighting coefficient (after normalized with total VE or VH  $\chi^{(2)}$  value) to sum the probability densities of all occupied or unoccupied states. Therefore, this method ensures that quantum states which cause SHG can be shown together as these occupied or unoccupied "SHG-densities", while states irrelevant to SHG will not be shown. Therefore, the origin of SHG optical nonlinearity can be highlighted in the real space through the resulting distribution of such densities. The methods have been employed successfully to analyze the SHG origin of NLO borates  $Li_nM_{n-1}B_{2n-1}O_{4n-2}(M=Cs/Rb, n=3,4,6)^{49}$  and  $Bi_2ZnOB_2O_6^{51}$ .

#### **Results and Discussion**

#### Deep Ultraviolet Transmission Spectrum

Ultraviolet cut-off edge of a NLO crystal is an important indicator of its practical application range. Two large SrBPO<sub>5</sub> and BaBPO<sub>5</sub> crystals were grown and shown in Figure 1. In order to obtain their cut-off edges accurately, the UV transmission spectra of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> crystals were measured in nitrogen. From the spectra, we can see that the transparencies of the SrBPO<sub>5</sub> and BaBPO<sub>5</sub> crystals are above 80% at until 200 and 209 nm, respectively, and decreases starting from 200 and 209 nm, and reaches zero at 180 and 185 nm, respectively.



Figure 1. The ultraviolet (UV) transmission spectrum and crystal photographs o  $SrBO_5$  (a) and  $BaBPO_5$  (b).

#### **Birefringence and Phase Matching Curves**

According to the point-group symmetry of D<sub>3</sub>, the SrBPO<sub>5</sub> and BaBPO<sub>5</sub> crystals are uniaxial and there are only two independent nonzero diagonalizable of dielectric tensors. The uniaxial properties of them were measured by conoscope using a crystal slicing perpendicular to optical axis. Interference patterns were shown in Figure S2. The square of the refractive index **n** is equal to the real part of  $\varepsilon$  ( $\omega$ ). The birefringence can be obtained from the linear response functions. Figure 2 shows the calculated and experimental dispersion curves of refractive indices and birefringence. We can see that the birefringence  $\Delta n$ , defined as  $n_0 - n_e$ , is about 0.018 for SrBPO<sub>5</sub> and 0.026 for BaBPO<sub>5</sub> at 1064 nm. The calculated results are consistent well with the experimental values. As shown in Figure 2, because of small dispersion of refractive indices, we can predict that SrBPO<sub>5</sub> and BaBPO<sub>5</sub> could better fulfil the phase-matching conditions.



Figure 2. The calculated and experimental dispersion curves of birefringence and experimental refractive index (insert) of SrBPO<sub>5</sub> (a) and BaBPO<sub>5</sub> (b).

Type I phase matching (PM) SHG curves of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> were calculated according to the Sellmeier equations<sup>20</sup>, <sup>21</sup> as a function of fundamental wavelength (in Figure S3). The Sellmeier equations indicate that the shortest type I PM SHG wavelengths are 395 nm for SrBPO<sub>5</sub> and 364 nm for BaBPO<sub>5</sub> respectively. Obviously, the shorted type I phase matching (PM) SHG wavelength of BaBPO<sub>5</sub> is lower than that of SrBPO<sub>5</sub>.

#### **Thermal Properties**

The thermal expansion of a NLO crystal is an important factor in its growth and applications<sup>52</sup>. Light absorption by a crystal causes a thermal gradient that may disturb the laser oscillation, and high thermal gradients can also lead to crystal fracture. The thermal expansions of a- and c-axis of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> are measured ranging 50 to 300 °C, shown in Figure 3. From this figure, the thermal expansion curves demonstrate that no anomaly within the measuring temperature range is observed and the curves are linear within this range. The average linear

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thermal expansion coefficients of the a- and c-oriented in SrBPO<sub>5</sub> and BaBPO<sub>5</sub> crystals are  $7.66 \times 10^{-6}$ /°C,  $7.81 \times 10^{-6}$ /°C and  $8.72 \times 10^{-6}$ /°C,  $7.82 \times 10^{-6}$ /°C, respectively.

From the crystal structure of both compounds, one can expect that the thermal expansion coefficients of both compounds would show a small anisotropy along a- and c-axes. This is in agreement with our experimental results, thus both crystals are not cracked during the crystal growth.

The DTA curves of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> were shown in Figure S4 measured from 900 to 1300 °C for SrBPO<sub>5</sub> and 900 to 1250 °C for BaBPO<sub>5</sub>. As shown in the DTA curves, there are two endothermic peak at 1220 and 1238 °C for SrBPO<sub>5</sub> and two endothermic peaks at 1203 and 1121 °C for BaBPO<sub>5</sub>. These results further indicate that both compounds are incongruent melting compounds. Therefore, the flux method is necessary for the purpose of their crystal growth.



Figure 3. The thermal expansions of a- and c-axis of SrBPO<sub>5</sub> (a) and BaBPO<sub>5</sub> (b).

#### **Optical Uniformity Measurement**

Optical homogeneity of the crystal (Figure S5) is also an important indicator of practical application. Therefore, a single crystal with a size of  $3.50 \times 3.50 \times 3.45 \text{ mm}^3$  of SrBPO<sub>5</sub> and a size of  $3.50 \times 3.50 \times 3.45 \text{ mm}^3$  of BaBPO<sub>5</sub> with a laser of

wavelength of 632.8 nm were measured in this experiment. The values of optical uniformity are  $1.26 \times 10^{-5}$  /cm (SrBPO<sub>5</sub>) and  $2.48 \times 10^{-5}$  /cm (BaBPO<sub>5</sub>), which indicates that both crystals have high qualities.

#### **Electronic Structure**

The band structures of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> are also very similar. SrBPO<sub>5</sub> and BaBPO<sub>5</sub> are direct gap (Figure S6) crystals with the calculated band gaps of 6.15 and 5.89 eV, as shown in Table 1. Comparing with the optical experimental gaps 6.44 (SrBPO<sub>5</sub>) and 6.14 eV (BaBPO<sub>5</sub>), the calculated gaps were in agreement very well. And the very small difference between the calculated and the experimental ones is because of the discontinuity of exchange-correlation energy. To get linear and NLO optical properties more accurately, we need the resonances occurring at the correct energies. The scissors operator will be applied to the computation of optical properties.

Figure 4 shows the partial density of states (PDOS) of SrBPO<sub>5</sub> and BaBPO<sub>5</sub>. For SrBPO<sub>5</sub>, the main occupant is O-2p orbital in the VBs near the Fermi surface and the Sr-4p orbitals at the bottom of the CBs, which suggests that the Sr-O bonds determine the band gap. Differently, in BaBPO<sub>5</sub>, Ba-5d orbital is dominant at the bottom of CBs. It means that the Ba-O bond controls the band gap of BaBPO<sub>5</sub>. Therefore the difference between electronic structures of Sr and Ba makes a red shift about 0.17 eV for BaBPO<sub>5</sub> comparing with SrBPO<sub>5</sub>.

Table 1. The calculated and experimental band gaps of SrBPO<sub>5</sub> and BaBPO<sub>5</sub>.

Crystal	Calcd.	Expel.	Difference
SrBPO <sub>5</sub> (eV)	6.15	6.44	0.29
BaBPO <sub>5</sub> (eV)	5.98	6.14	0.16





**Figure 4.** The PDOS of SrBPO<sub>5</sub> (a) and BaBPO<sub>5</sub> (b). I-V regions refer to the negative contribution region, the main contribution region in VBs, the main contribution region in CBs, the offset contribution to the SHG coefficient, the second contribution in CBs.

#### **NLO Properties**

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We calculated SHG coefficients  $d_{ii}$  under the static limit within the length gauge. According to the  $D_3$  point-group symmetry and Kleinman symmetry, only  $d_{11}$  should be determined. The experimental SHG intensities and computed ones at combinations of exchange-correlation functional and pseudopotentials are shown in Table 2. The result, calculated on the condition of GGA and NCP, agrees well with the experimental result, which proves the validity of our studies on the SrBPO<sub>5</sub> and BaBPO<sub>5</sub> with GGA plane-wave pseudopotential method.

Table 2. Comparisons of the calculated SHG coefficients with a correction o
the band gap and experimental SHG effect of SrBPO5 and BaBPO5.

Crystal	Expel.	Calcd. $d_{11}$ (pm/V)	VE	VH	
SrBPO <sub>5</sub>	0.57KDP	0.218(0.56KDP)	0.268	-0.05	
BaBPO <sub>5</sub>	0.43KDP	0.157(0.40KDP)	0.137	0.02	

#### SHG Response in MBPO<sub>5</sub>

#### **Distribution of the Electron States to SHG Response**

For the process of NLO effects, the short-range forces rather than long-range interactions play a decisive role. In other words, in the NLO effects, the electron motion may be regarded as confined to small regions and any NLO susceptibility (or second-order susceptibility) in crystals is a localized effect arising from the action of incident photons on the electrons in certain orbitals of atomic clusters<sup>30</sup>. In this work, to study the distribution of the electron states in SHG response, the integral contribution<sup>49</sup> of the band-resolved  $\chi^{(2)}$  in VE and VH processes and the SHG-density were calculated.

Figure 4 shows the partial density of states (PDOS) and integral of band-resolved  $\chi^{(2)}$  of SrBPO<sub>5</sub> and BaBPO<sub>5</sub>, which counts the integral contribution of SHG effect in the energy representation. Here we choose BaBPO<sub>5</sub> as a demonstration to locate certain orbital of atomic clusters using the band-resolved method. According to the variation of integral of band-resolved  $\chi^{(2)}$  (green curves in Figure 4), the PDOS was divided into several regions in energy. In the region I (-3.81 eV $\sim$  -2.01 eV) in Figure 4a, the electrons of  $O1-p_z$  (the nonbonding p orbital) and the bonding orbital of O2 occupy this energy region and the integral of band-resolved  $\chi^{(2)}$  decrease, which suggests that the contribution of this region is negative. Meanwhile, the electrons of the nonbonding p orbital of O2 and O3 atom occupy the region II (-2.01~0.00 eV), and the integral of band-resolved  $\chi^{(2)}$ increases which corresponds to positive contributions to SHG effect. Similarly, in the region III (6.3~8.6 eV), the most part is Ba-5d orbital and it is the main positive contribution in CBs according to the curve of integral of band-resolved  $\chi^{(2)}$ .

Except for the contribution of electronic states within energy band framework, the electronic structure subsystem which causes SHG can be visualized via the SHG-density method. According to the results shown in Table 2, the VE process would be analysed due to its domination in the SHG response in BaBPO<sub>5</sub>. Interestingly, different microscopic groups or atoms exhibit different contributions: the PO<sub>4</sub> groups give a negative contribution (Figure 5a) to SHG effect, while the BO<sub>4</sub> groups and metal cations own positive contributions (Figures 6b-6d). To clarify such counteraction from different parts, we studied the main contribution region and corresponding orbitals in energy. Figure 5a shows the counteractive contributor in the region I which corresponds to 2p orbitals of oxygen in PO<sub>4</sub>. We can see that orbital and negative SHG density have a great overlap. In other words, the p-electron orbital of oxygen in PO<sub>4</sub> groups, which play the counteractive role of SHG effect. Oppositely, we can see the positive contributions which come from the BO<sub>4</sub> groups and are corresponding to p orbitals of O3 in Figure 5b. Figure 5c shows the contribution of the region III (6.3 eV~8.6 eV). The SHG density sprinkles on Ba-5d orbital but not on the B-2p and P-3p orbital, which indicates that the Ba-5d orbital is the main contributor in this region. Similarly, in the region V, the anti- $\sigma$ orbital of the B-O bond is the main contributor in SHG density, which illustrates the importance of BO<sub>4</sub> groups as shown in Figure 5d. In conclusion, the PO<sub>4</sub> groups have negative contributions while the BO4 groups and the Ba metal cations are the main contributors to SHG effect of BaBPO<sub>5</sub>.

The same methology was employed to analyze the SHG response of SrBPO<sub>5</sub>. The main difference from BaBPO<sub>5</sub> is that the counteraction contributions almost vanish in the region I. Meanwhile, we can find the same SHG response of BO<sub>4</sub> like Figure 5c in SrBPO<sub>5</sub> in region III, IV and V and this response has not been observed in PO<sub>4</sub>. That is to say, the BO<sub>4</sub> group is still the main contributor of SHG effect. In addition, compared the region III of SrBPO<sub>5</sub> and BaBPO<sub>5</sub> in Figure 4, owing to the absence of *d* orbital of the Sr atom (Figure 4b), the DOS of the B atom and the P atom increases. This change is bound to

whittle the contribution of metal cations and strengthen the contribution of  $BO_4$ . This phenomenon will be further confirmed by the real-space atom-cutting method in the next

section. Therefore, the  $BO_4$  groups become the main role in SHG effect of SrBPO<sub>5</sub>.



# **Figure 5.** The SHE-density of VE process for BaBPO<sub>5</sub>. (a) The negative contribution in SHG density of occupied states (orange) and the corresponding orbitals (green), (b) The positive contribution in SHG density of occupied states (orange) and the corresponding orbitals (green), (c) The positive contribution of unoccupied states (red) of Ba and the corresponding orbitals (green), (d) the positive contribution of unoccupied states (red) of BO<sub>4</sub> and the corresponding orbitals (green).

#### The Significance of d Orbital

Although we found the main contribution of SHG effect in MBPO<sub>5</sub>, there is still one question: why the counteractive contribution vanishes in SrBPO<sub>5</sub>. In the matter of crystal structure, SrBPO<sub>5</sub> and BaBPO<sub>5</sub> are isostructural and possess similar lattice parameters: a=7.12 Å, c=6.96 Å and a=6.84 Å, c=6.79 Å, respectively. The bond lengths and angles of BO<sub>4</sub> and PO<sub>4</sub> are almost the same. The radii of Ba and Sr atom are 2.78 Å and 2.45 Å. The radius difference of cation may cause the local distortion of the polyhedral and overall framework structures in some compounds such as ACuTe<sub>2</sub>O<sub>7</sub> (A = Sr2+,Ba2+,or Pb<sup>2+</sup>)<sup>53</sup>, ANaNbOF<sub>5</sub> (A=K, Cs)<sup>54</sup>,

AMoO<sub>3</sub>(IO<sub>3</sub>)(A=K, Rb, Cs)<sup>55</sup>, AGa(SeO<sub>3</sub>)<sub>2</sub>(A = Li, Na, K, and Cs)<sup>56</sup>, A<sub>2</sub>Ti(IO<sub>3</sub>)<sub>6</sub>(A=Li, Na, K, Rb, Cs, Tl)<sup>57</sup> and MM'Be<sub>2</sub>B<sub>2</sub>O<sub>6</sub>F (M=Na, M'=Ca; M=K, M'=Ca, Sr)<sup>58</sup>. In this work, we employed Gaussian<sup>59</sup> to calculate the dipole moments of MO polyhedra and the result suggests that there is no difference in SrBPO<sub>5</sub> and BaBPO<sub>5</sub>. Therefore, we think that the radius difference of cation will not cause the local distortion of the tetrahedral and overall framework structures and also cannot cause different SHG effect of metal and PO<sub>4</sub> group. In fact, the dangling bond of the terminal oxygen exists only in PO<sub>4</sub> and is easily influenced by the metal cations, which means that metal cations make great difference to PO<sub>4</sub> rather than BO<sub>4</sub>.

The influence of the metal cations to the terminal oxygen (O2 for BaBPO<sub>5</sub> and O1 for SrBPO<sub>5</sub>) and boron-phosphorus bridge oxygen (O1 for BaBPO<sub>5</sub> and O2 for SrBPO<sub>5</sub>) in PO<sub>4</sub> can be reflected in the lowest unoccupied molecular orbital (LUMO, Figure 6). It is noted that the interaction between terminal oxygen or boron-phosphorus bridge oxygen in PO<sub>4</sub> and metal cation is stronger than that between boron-boron bridge oxygen O3 in BO<sub>4</sub> and metal cation. More importantly, the electronic structure and PDOS show that d orbitals of the Ba cations dominate in LUMO, while B and P dominate in LUMO in SrBPO<sub>5</sub>. This suggests that, the interaction between oxygens and Ba cations in BaBPO<sub>5</sub> is stronger than that in SrBPO<sub>5</sub>. Thus, the Ba-5d orbital is closely related to the properties of  $PO_4$ . And owing to the absence of d orbital of Sr, the counteractive contribution from PO<sub>4</sub> vanishes in SrBPO<sub>5</sub>. There is no wonder that the contribution of PO<sub>4</sub> in SHG effect in SrBPO<sub>5</sub> and BaBPO<sub>5</sub> are different. Meanwhile, the Ba cations because of their d orbitals have more contribution in SHG effect in BaBPO<sub>5</sub>.



Figure 6. The LUMO of SrBPO<sub>5</sub> (a) and BaBPO<sub>5</sub> (b).

#### Spatial Contributions of Groups and Ions to SHG Response

Strangely enough, it is believed previously that if there are PO<sub>4</sub> and BO<sub>4</sub> together, the PO<sub>4</sub> group should be the main contributor to the SHG effect<sup>20</sup>. Perhaps they do not take microstructure into consideration. In order to verify the contribution of Ba and BO<sub>4</sub> groups and the counteractive of PO<sub>4</sub>, the real-space atom-cutting method<sup>51</sup> was employed in our work. In the "cutting", it is of importance to determine the suitable cutting radii of Ba, B, P and O1-O3. Owing to the charge-density distributions and the overlap behaviours in these compounds, the cutting radii of Sr, Ba, B, P, O are 1.80, 1.80, 0.82, 1.52, 1.11 Å, respectively. According to Rietveld technique, for BaBPO<sub>5</sub>, the anionic groups are BO<sub>4</sub> and PO<sub>4</sub>, not  $BPO_7^{60}$  and its decomposed products are  $Ba_3BP_3O_{12}$  and  $Ba_2P_2O_7$ . Hence,  $BO_4$  or  $PO_4$  can be regarded as a group to be cut and the bridge oxygen is assigned to PO<sub>4</sub> group because it has stronger interaction with phosphorus than boron according to the decomposed products. Consequently, the contributions are:  $d_{11}(Ba) = -0.11 \text{ pm/V}, d_{11}(PO_4) = 0.20 \text{ pm/V}, d_{11}(BO_4) = -$ 0.26 pm/V. It is worth noting that the total value of  $d_{11}$  of BaBPO<sub>5</sub> is negative (For convenience, we convert the value of  $d_{11}$  to positive in the band-resolved analysis of Figure 4 and Table 2). So the contribution of  $PO_4$  is counteractive. The cutting results of SrBPO<sub>5</sub> are as expected:  $d_{11}(PO_4) = 0.03$  $d_{II}(BO_4) = 0.20 \text{ pm/V}, d_{II}(Sr) = 0.04 \text{ pm/V}.$ pm/V, Consequently, in SrBPO<sub>5</sub>, the PO<sub>4</sub> groups have a very tiny contribution.

The results obtained from the real-space atom-cutting method confirm the contributions of different groups or ions. The curious effect from the metal cations is revealed further: i) direct contribution from the Ba ions is more apparent than that from the Sr ions, which is due to the difference from the electron states; ii) indirect influence from metal cations to the BO<sub>4</sub> and PO<sub>4</sub> groups leads to dominant action of BO<sub>4</sub> in both crystals, and a counteractive contribution of the PO<sub>4</sub> groups in BaBPO<sub>5</sub> but a positively tiny contribution in SrBPO<sub>5</sub>.

#### Conclusions

In summary, electronic structure and optical properties of  $MBPO_5$  were studied theoretically and experimentally. The large crystal of  $SrBPO_5$  and  $BaBPO_5$  have been successfully grown by top-seeded solution growth method. Additional measurements, such as optical uniformity and thermal expansion measurements, were made. The results demonstrate that  $SrBPO_5$  and  $BaBPO_5$  have good optical qualities. We employed the band-resolved method, SHG-density method, real-space atom-cutting method and band-resolved method to analyze the NLO properties. The result suggests that the main contribution of SHG in  $BaBPO_5$  is  $BO_4$  and the Ba cations while the main NLO-active units in  $SrBPO_5$  are almost  $BO_4$  groups. Fallaciously, the  $PO_4$  groups do not undertake the main role. On the contrary, it has the counteractive effect in  $BaBPO_5$ . Remarkably, through analysing the mechanism of the origin of

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SHG effects in MBPO<sub>5</sub>, we find that apart from  $BO_4$  and  $PO_4$ , metal cations such as Ba in BaBPO<sub>5</sub> may have an important role in SHG effect. In addition, although  $BO_4$  and  $PO_4$  can be regarded as the NLO-active contribution candidates, whether they could make contribution in the SHG responses depends on the coordination environments and also the cations.

In addition, from this work, we can see that the contribution of the  $BO_4$  groups and metal cations to SHG effect in some cases should not be ignorable, which may enlighten the design and search of new excellent NLO crystals. Taking BaBPO<sub>5</sub> as the example, if the PO<sub>4</sub> groups do not exhibit counteractive contribution to SHG effect, the SHG effect of BaBPO<sub>5</sub> will be about as large as that of KDP. Hence, a full understanding of the mechanism of NLO effects can be helpful to design and search new excellent NLO crystals.

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#### Notes and references

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- 1. J. J. De Yoreo, A. K. Burnham and P. K. Whitman, *Int. Mater. Rev.*, 2002, **47**, 113.
- 2. V. G. Dimitriev, Springer: Berlin, 1991.
- 3. A. H. Reshak, I. V. Kityk and S. Auluck, *J. Phys. Chem. B*, 2010, **114**, 16705.
- 4. C. T. Chen, B. Wu, A. Jiang and G. You, *Sci. Sin. Ser. B*, 1985, **28**, 235.
- C. T. Chen, Y. C. Wu, A. D. Jiang, B. C. Wu, G. M. You, R. K. Li and S. J. Lin, *J. Opt. Soc. Am. B*, 1989, 6, 616.
- 6. S. C. Wang, N. Ye, W. Li and D. Zhao, J. Am. Chem. Soc., 2010, **132**, 8779.
- H. Wu, S. Pan, K. R. Poeppelmeier, H. Li, D. Jia, Z. Chen, X. Fan, Y. Yang, J. M. Rondinelli and H. Luo, *J. Am. Chem.* Soc., 2011, 133, 7786.
- 8. H. Wu, H. Yu, S. Pan, Z. Huang, Z. Yang, X. Su and K. R. Poeppelmeier, *Angew. Chem. Int. Ed.*, 2013, **52**, 3406.
- H. Wu, H. Yu, Z. Yang, X. Hou, X. Su, S. Pan, K. R. Poeppelmeier and J. M. Rondinelli, *J. Am. Chem. Soc.*, 2013, 135, 4215.
- S. Zhao, P. Gong, L. Bai, X. Xu, S. Zhang, Z. Sun, Z. Lin, M. Hong, C. Chen and J. Luo, *Nat. Commun*, 2014, 5, 4019.

- C. T. Chen, Z. Y. Xu, D. Q. Deng, J. Zhang, G. K. L. Wong,
  B. C. Wu, N. Ye and D. Y. Tang, *Phys. Rev. Lett.*, 1996, 68, 2930.
- C. T. Chen, N. Ye, J. Lin, J. Jiang, W. Zeng and B. Wu, *Adv. Mater.*, 1999, 11, 1071.
- 13. P. Yu, L. M. Wu, L. J. Zhou and L. Chen, *J. Am. Chem. Soc.*, 2014, **136**, 480.
- S. Zhao, P. Gong, S. Luo, L. Bai, Z. Lin, C. Ji, T. Chen, M. Hong and J. Luo, *J. Am. Chem. Soc.*, 2014, **136**, 8560.
- 15. R. Kniep, Angew. Chem. Int. Ed., 1994, 106, 791.
- 16. R. Kniep, Angew. Chem. Int. Ed., 1999, 3857.
- 17. T. Yang, J.-L. Sun, G.-B. Li and L.Eriksson, *Chem. Eur. J.*, 2008, **14**, 7212.
- D.Zhao, W.-D. Cheng, H. Zhang, S.-P. Huang and Z. Xie, *Inorg. Chem.*, 2009, 48, 6623.
- R. Kniep, H. Engelhardt and C. Hauf, *Chem. Mater.*, 1998, 10, 2930.
- 20. S. Pan, Y. Wu, P. Fu, G. Zhang, Z. Li, C. Du and C. T. Chen, *Chem. Mater.*, 2003, **15**, 2218.
- 21. S. Pan, Y. Wu, P. Fu, X. a. Wang, G. Zhang and C. T. Chen, *J. Opt. Soc. Am. B*, 2004, **21**, 761.
- 22. Zhihua Li, Z. Lin, Y. Wu, P. Fu, Z. Wang and C. Chen, *Chem. Mater.*, 2004, **16**, 2906.
- R. P. Bontchev and S. C. Sevov, *Inorg. Chem.*, 1996, 35, 6910.
   B. Ewald, Y.-X. Huang and R. Kniep, *Z. Anorg. Allg. Chem.*,
  - B. Ewald, Y.-X. Huang and R. Kniep, Z. Anorg. Allg. Chem., 2007, 633, 1517.
- R. Kniep, H. Engelhardt and C. Hauf, *Chem. Mater.*, 1998, 10, 2930.
  - Y. Wang, S. Pan and Y. Shi, *Chem. Eur. J.*, 2012, **18**, 12046. X. Zhang, L. Wang, S. Zhang, G. Wang, S. Zhao, Y. Zhu, Y.
- X. Zhang, L. Wang, S. Zhang, G. Wang, S. Zhao, Y. Zhu, Y. Wu and C. Chen, *J. Opt. Soc. Am. B*, 2011, 18, 2236.
- H. Ehrenberg, S. Laubach, P. C. Schmidt, R. McSweeney, M. Knapp and K. C. Mishra, J. Solid State Chem., 2006, 179, 968.
   W. Yao, R. He, X. Wang, Z. Lin and C. Chen, Adv. Opt.
  - W. Yao, R. He, X. Wang, Z. Lin and C. Chen, *Adv. Opt. Mat.*, 2014, **2**, 411.
- C. T. Chen, Y. Wu and R. Li, *Int. Rev. In Phys. Chem*, 1989, 8, 65.
- W.-L. Zhang, W.-D. Cheng, H. Zhang, L. Geng, C.-S. Lin and Z.-Z. He, *J. Am. Chem. Soc.*, 2010, **132**, 1508.
  - Y.-Z. Huang, L.-M. Wu, X.-T. Wu, L.-H. Li, L. Chen and Y.-F. Zhang, J. Am. Chem. Soc., 2010, 132, 12788.
  - . R. He, Z. S. Lin, T. Zheng, H. Huang and C. T. Chen, *J Phys Condens Matter*, 2012, **24**, 145503.
- L. Kang, Z. Lin, J. Qin and C. Chen, *Sci Rep*, 2013, **3**, 1366.
   R. He, H. Huang, L. Kang, W. Yao, X. Jiang, Z. Lin, J. Qin
- 35. R. He, H. Huang, L. Kang, W. Yao, X. Jiang, Z. Lin, J. Qir and C. Chen, *Appl. Phys. Lett.*, 2013, **102**, 231904.
- Z. G. Hu, T. Higashiyama, M. Yoshimura, Y. K. Yap, Y. Mori and T. Sasaki, *Jpn. J. Appl. Phys.*, 1998, **37**, L1093.
- M. He, L. Kienle, A. Simon, X. L. Chen and V. Duppel, J. Solid State Chem., 2004, 177, 3212.
   C. T. Chen, Y. B. Wang, B. C. Wu, K. Wu, W. L. Zeng and
  - C. T. Chen, Y. B. Wang, B. C. Wu, K. Wu, W. L. Zeng and L. H. Yu, *Nature*, 1995, **373**, 322.
  - H. W. Huang, J. Y. Yao, Z. H. Lin, X. Y. Wang, W. J. Yao, N. X. Zhai, C. T. Chen and R. He, *Chem. Mater.*, 2011, 23, 5457.
  - S. J. Clark, M. D. Segall, C. J. Pickard, P. J. Hasnip, M. J. Probert, K. Rrfson and M. C. Payne, *Z. Kristallogr.*, 2005, **220**, 567.
  - R. W. Godby, M. Schluter and L. J. Sham, *Phys. Rev. B*, 1988, **37**, 10159.
  - C. S. Wang and B. M. Klein, *Phys. Rev. B*, 1981, **24**, 3417.
  - M. S. Hybertsen and S. G. Louie, *Phys. Rev. B*, 1986, 24, 5390.
  - S. N. Rashkeev, W. R. L. Lambrecht and B. Segall, *Phys. Rev. B*, 1998, **57**, 3905.
  - R. W. Godby, M. Schlueter and L. J. Sham, *Phys. Rev. B*, 1988, **37**, 10159.
  - O. Gunnarsson and K. Schoenhammer, *Phys. Rev. Lett.*, 1986, **56**, 1968.
  - C. Aversa and J. E. Sipe, Phys. Rev. B, 1995, 52, 14636.

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33.

39.

40

41.

42.

43.

44

45.

46.

47.

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- 48. J. Lin, M.-H. Lee, Z.-P. Liu, C. J. Pickard and C. Chen, Phys. Rev. B, 1999, 60, 13380.
- 49. B. Zhang, Z. Yang, Y. Yang, M.-H. Lee, S. Pan, Q. Jing and X. Su, J. Mater. Chem. C, 2014, 2, 4133.
- 50. C.-h. Lo, M. D. thesis and T. University, 2005.
- X. Su, Y. Wang, Z. Yang, X.-C. Huang, S. Pan, F. Li and 51. M.-H. Lee, J. Phys. Chem. C 2013, 117, 14149
- 52. W. B. Hou, D. Xu, D. R. Yuan, M. G. Liu, N. Zhang, X. T. Tao, S. Y. Sun and M. H. Jiang, Cryst. Res. Technol., 1994, 29, 939.
- 53. J. Yeon, S. H. Kim, M. A. Hayward and P. S. Halasyamani, Inorg. Chem., 2011, 50, 8663.
- M. R. Marvel, J. Lesage, J. Baek, P. S. Halasyamani, C. L. 54. Stern and K. R. Poeppelmeier, J. Am. Chem. Soc., 2007, 129, 13963.
- 55. R. E. Sykora, K. M. Ok, P. S. Halasyamani and T. E. Albrecht-Schmitt, J. Am. Chem. Soc., 2002, 124, 9.
- 56. D. W. Lee and K. M. Ok, Inorg. Chem., 2013, 52, 5176.
- H.-Y. Chang, S.-H. Kim, K. M. Ok and P. S. Halasyamani, J. 57. Am. Chem. Soc., 2009, 131, 6865.
- H. Huang, J. Yao, Z. Lin, X. Wang, R. He, W. Yao, N. Zhai 58. and C. Chen, *Chem. Mat.*, 2011, **23**, 5457. Gaussian 09, Revision C.01, M. J. Frisch, G. W. Trucks, H.
- 59. B. Schlegel, G. E. Scuseria, M. A. Robb, J. R. Cheeseman, G. Scalmani, V. Barone, B. Mennucci, G. A. Petersson, H. Nakatsuji, M. Caricato, X. Li, H. P. Hratchian, A. F. Izmaylov, G. Z. J. Bloino, J. L. Sonnenberg, M. Hada, M. Ehara, K. Toyota, R. Fukuda, J. Hasegawa, M. Ishida, T. Nakajima, Y. Honda, O. Kitao, H. Nakai, T. Vreven, J. A. Montgomery, J. E. Peralta, F. Ogliaro, M. Bearpark, J. J. Heyd, E. Brothers, K. N. Kudin, V. N. Staroverov, R. Kobayashi, J. Normand, K. Raghavachari, A. Rendell, J. C. Burant, S. S. Iyengar, J. Tomasi, M. Cossi, N. Rega, J. M. Millam, M. Klene, J. E. Knox, J. B. Cross, V. Bakken, C. Adamo, J. Jaramillo, R. Gomperts, R. E. Stratmann, O. Yazyev, A. J. Austin, R. Cammi, C. Pomelli, J. W. Ochterski, R. L. Martin, K. Morokuma, V. G. Zakrzewski, G. A. Voth, P. Salvador, J. J. Dannenberg, S. Dapprich, A. D. Daniels, O. Farkas, J. B. Foresman, J. V. Ortiz, J. Cioslowski and G. I. D. J. Fox, Wallingford CT,, 2009. 60.
  - Y. Shi, J. Liang, H. Zhang, Q. Liu, X. Chen, J. Yang, W. Zhuang and G. Rao, J. Solid State Chem., 1998, 135, 43.

### **Table of Contents graphic**

### Anomalous Second Harmonic Generation (SHG) Response in MBPO<sub>5</sub> (M=Sr, Ba)

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Based on SHG-density and band-resolve analysis, we find that  $BO_4$  groups and metal cation are the main contribution in SHG effect of MBPO<sub>5</sub> (M=Ba, Sr) but not the PO<sub>4</sub> groups as previously expected.